

UV-assisted alcohol sensors using GaN nanowires functionalized with ZnO and SnO₂

Ritu Bajpai^{1,2}, Abhishek Motayed^{2,3}, Albert Davydov², Kris A. Bertness⁴ and Mona Zaghloul¹
¹Department of Electrical and Computer Engineering, The George Washington University, Washington DC
²Material Measurement Laboratory, NIST, Gaithersburg, MD
³Institute for Research in Electronics and Applied Physics, University of Maryland, College Park, MD
⁴Physical Measurement Laboratory, National Institute of Standards and Technology, Boulder, CO

I. Motivation

Fabrication of nanowire gas sensors with low power, reduced size increased surface to volume ratio with added capability to

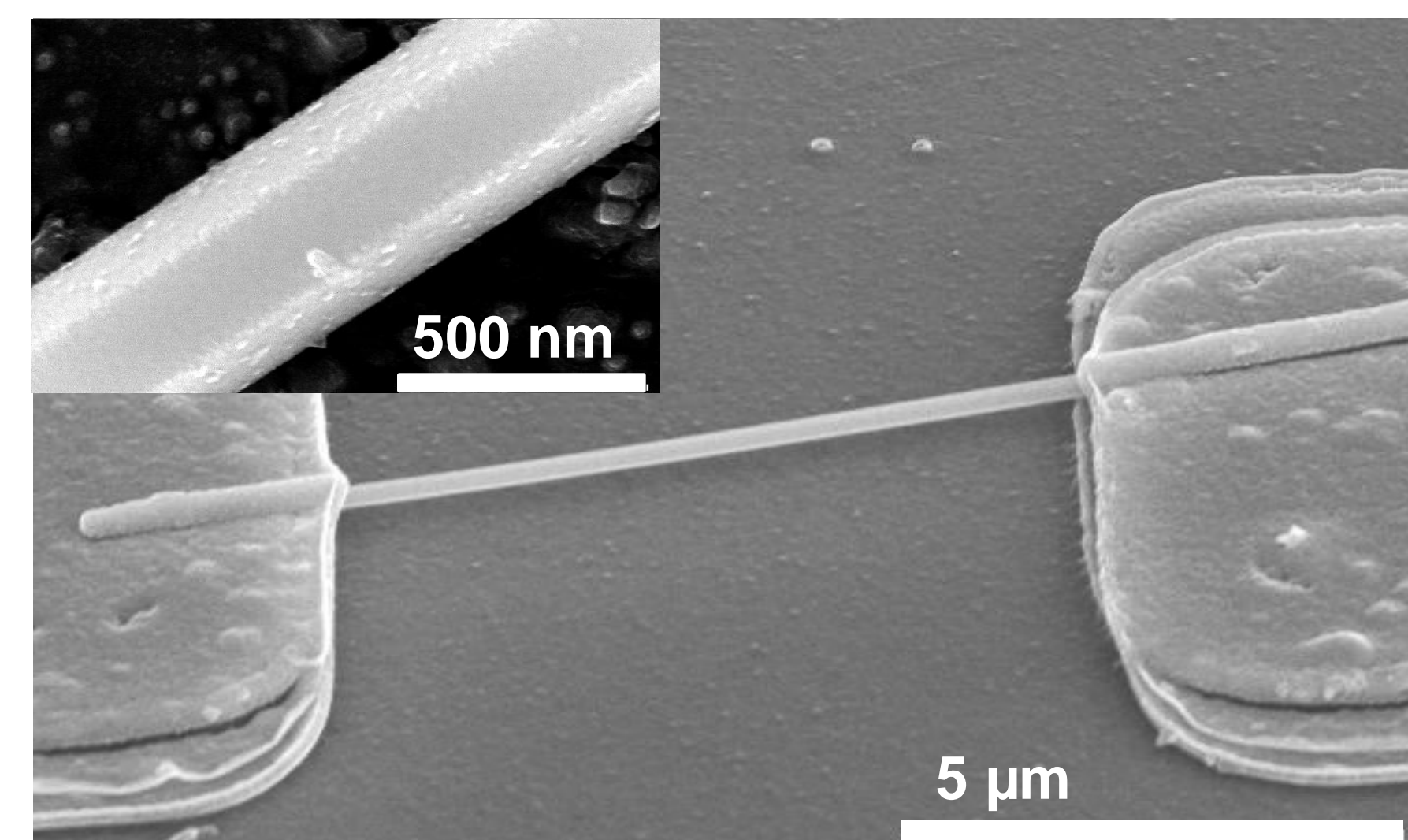
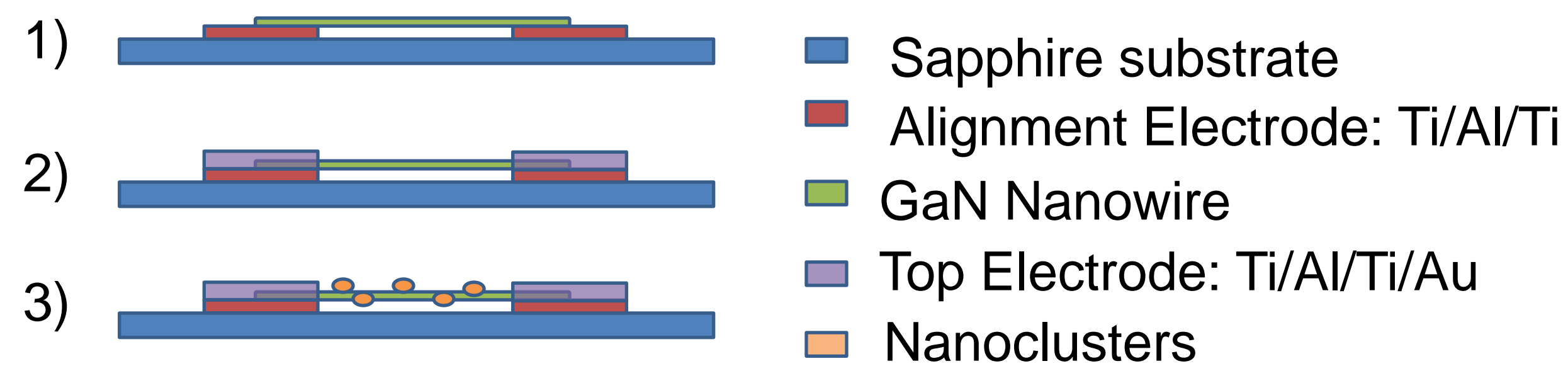
- Operate at room temperature
- Tune selectivity and sensitivity
- Make nano-sensor array

II. Highlights

- Chemically inert GaN nanowires (NW) functionalized with metal oxide nanoparticles
- UV light assisted sensing at room temperature
- ZnO and SnO₂ nanocluster coated GaN sensors are selective to alcohols.
- Sensitivity and selectivity tuned by light intensity

III. Device fabrication

- Photolithography for fabrication of electrodes
- Dielectrophoretic alignment of nanowires
- Rapid thermal anneal for ohmic contacts
- Sputter deposition for nanoparticle formation



SEM image of the NW bridge (inset- ZnO nanoclusters on the GaN NW)

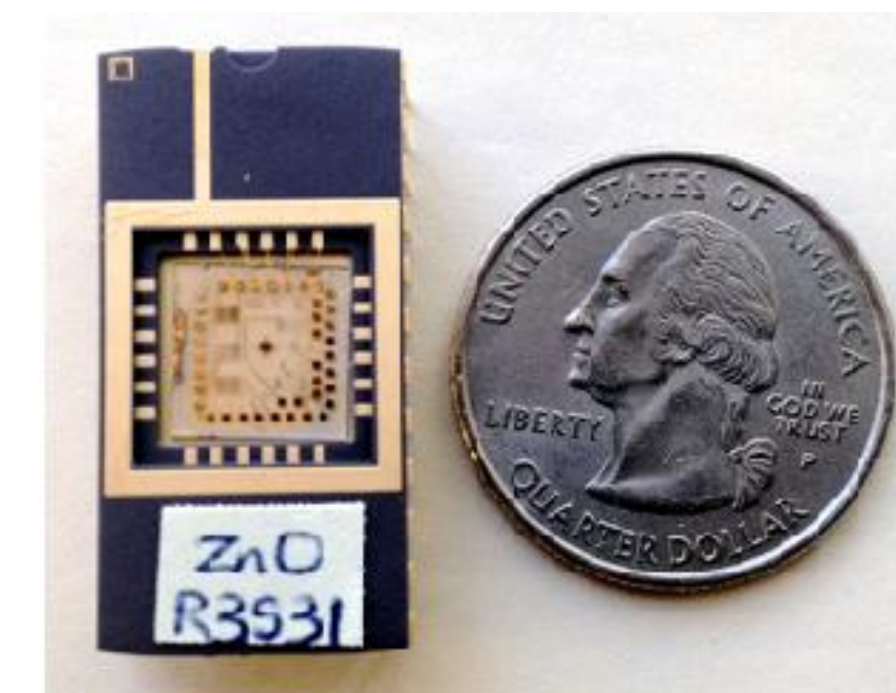
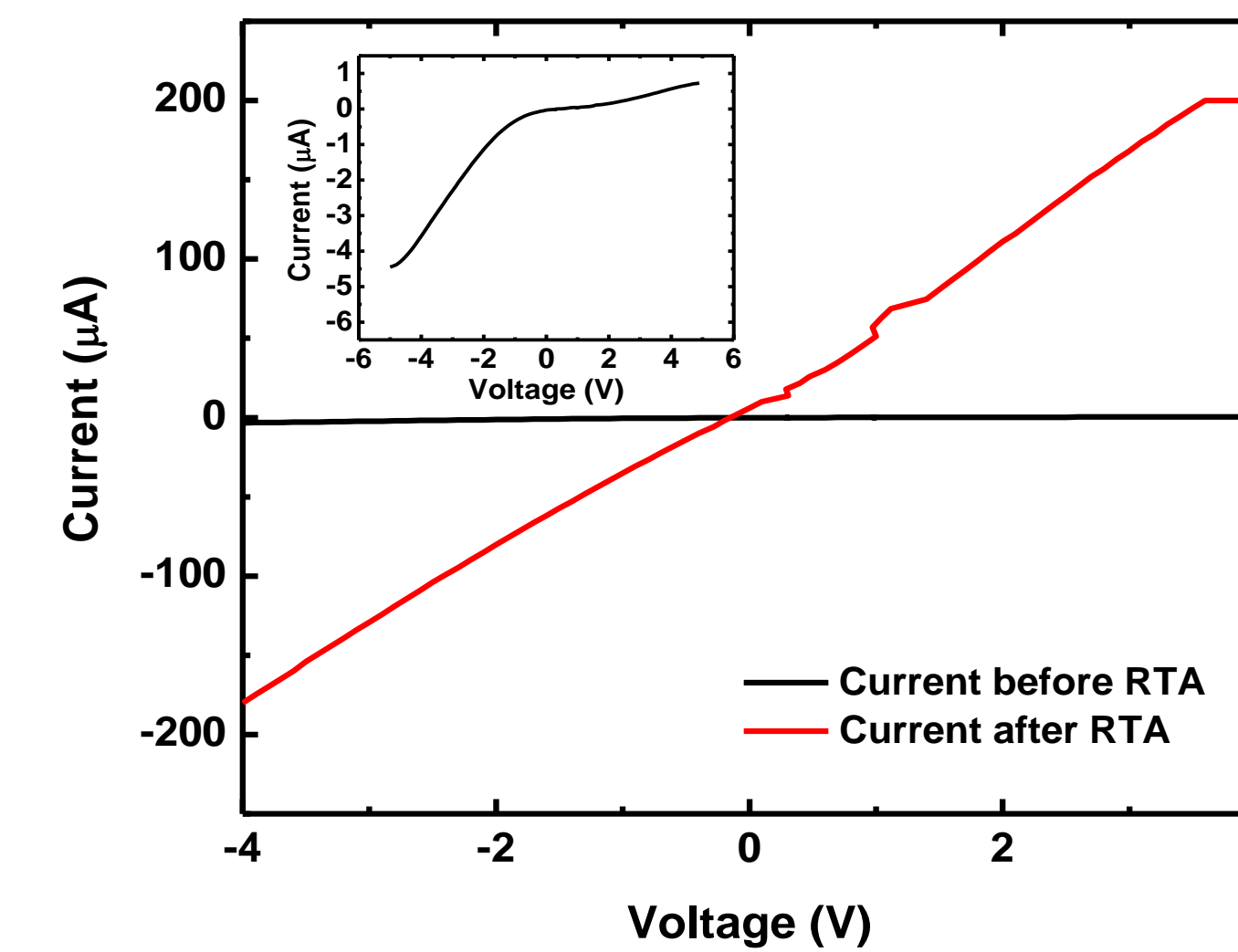
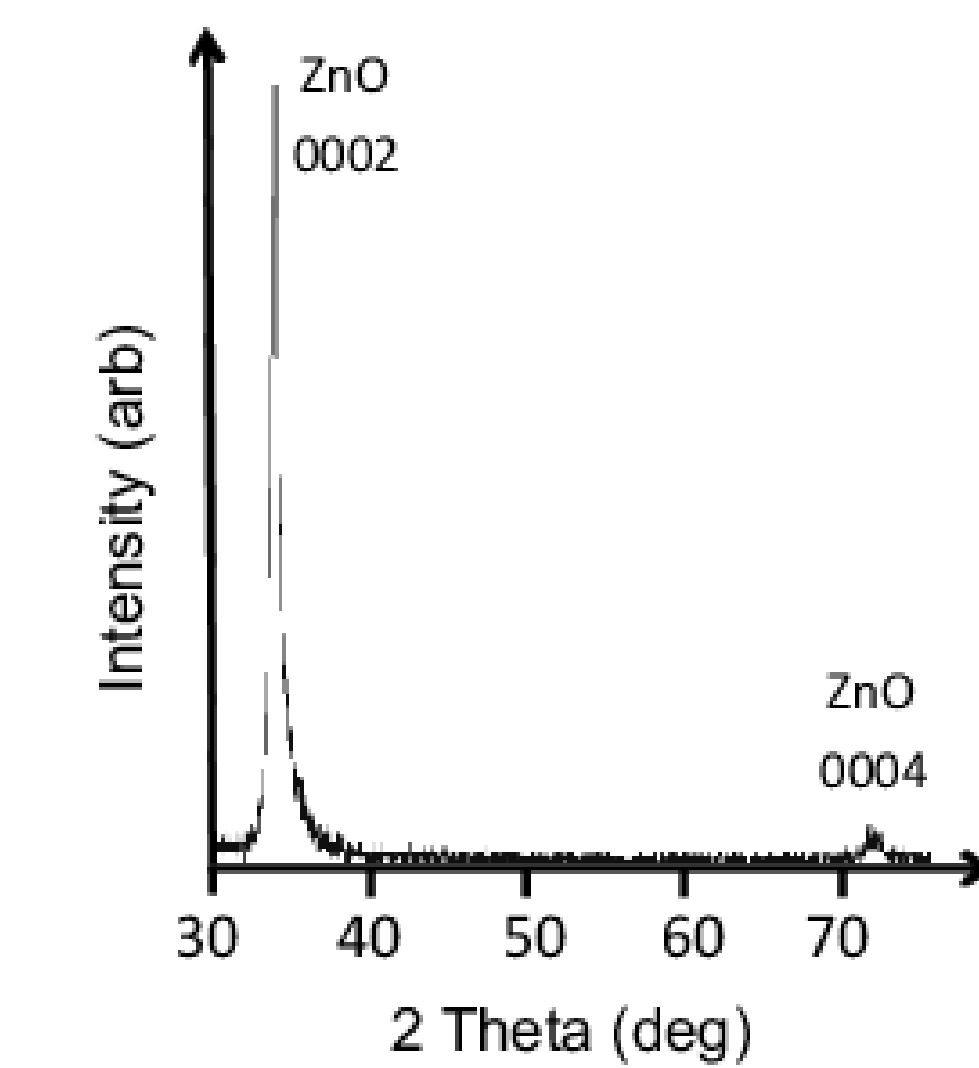


Image of a device wire bonded onto a chip carrier.

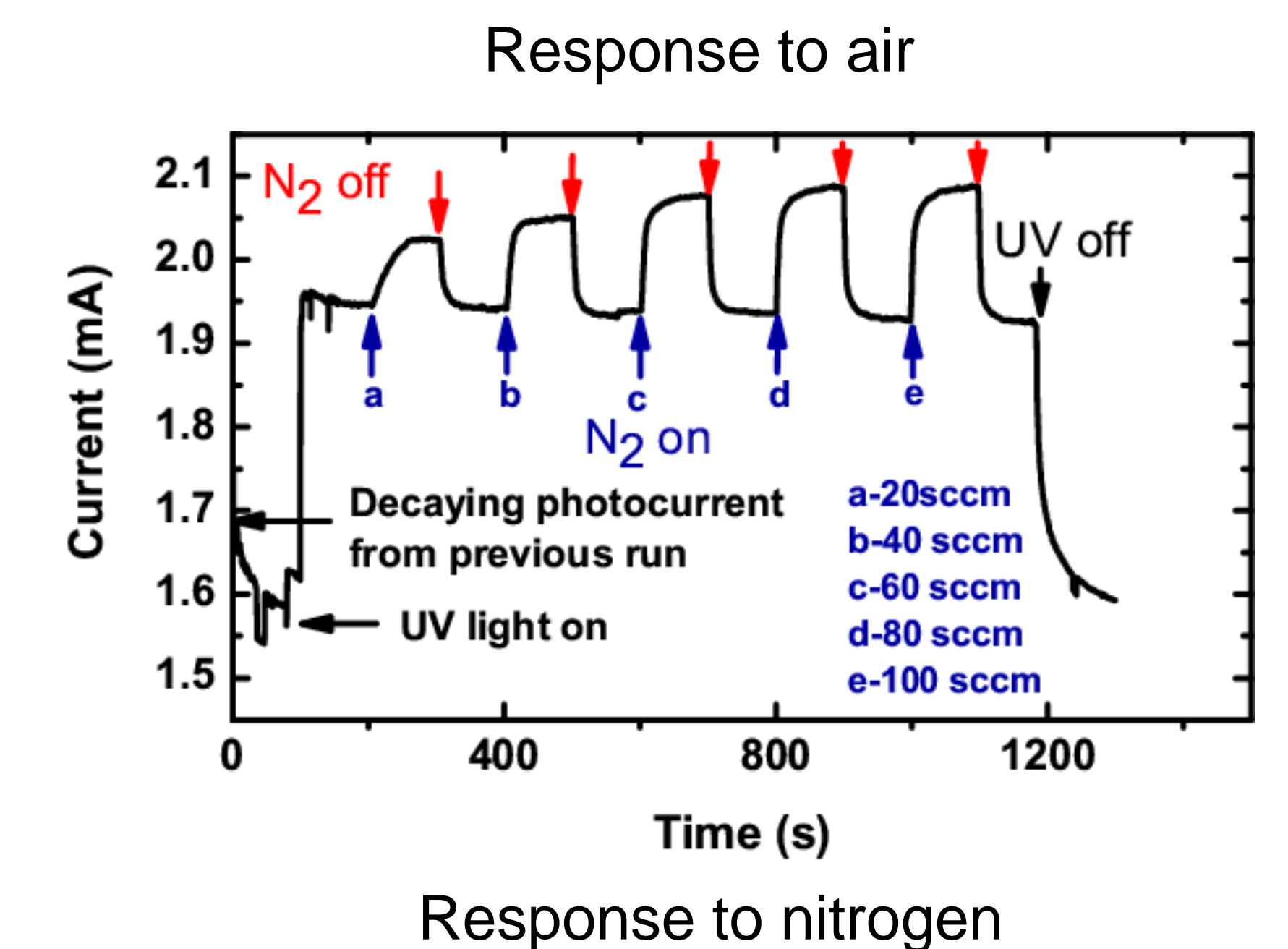
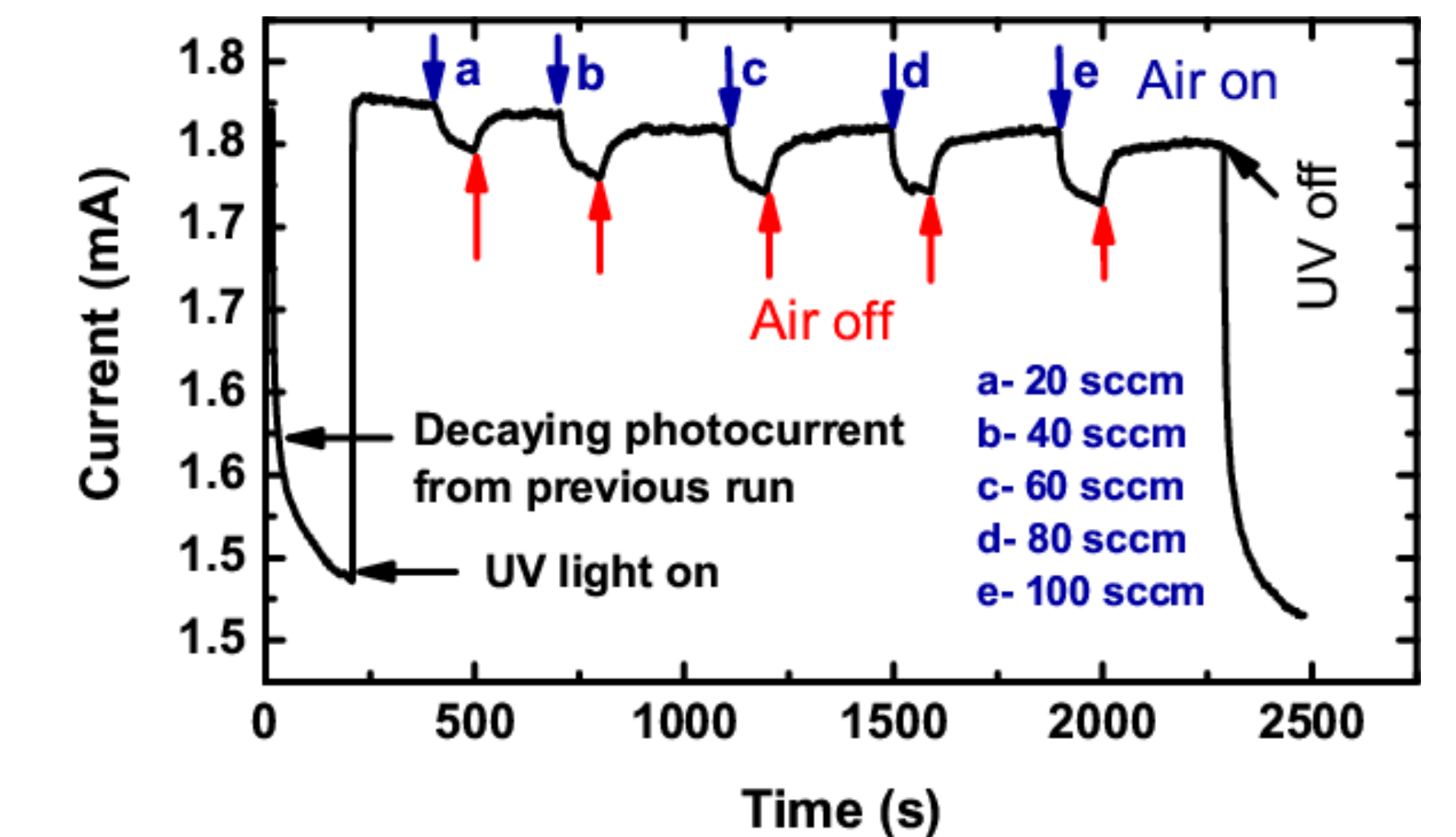


I-V characteristic of the device.

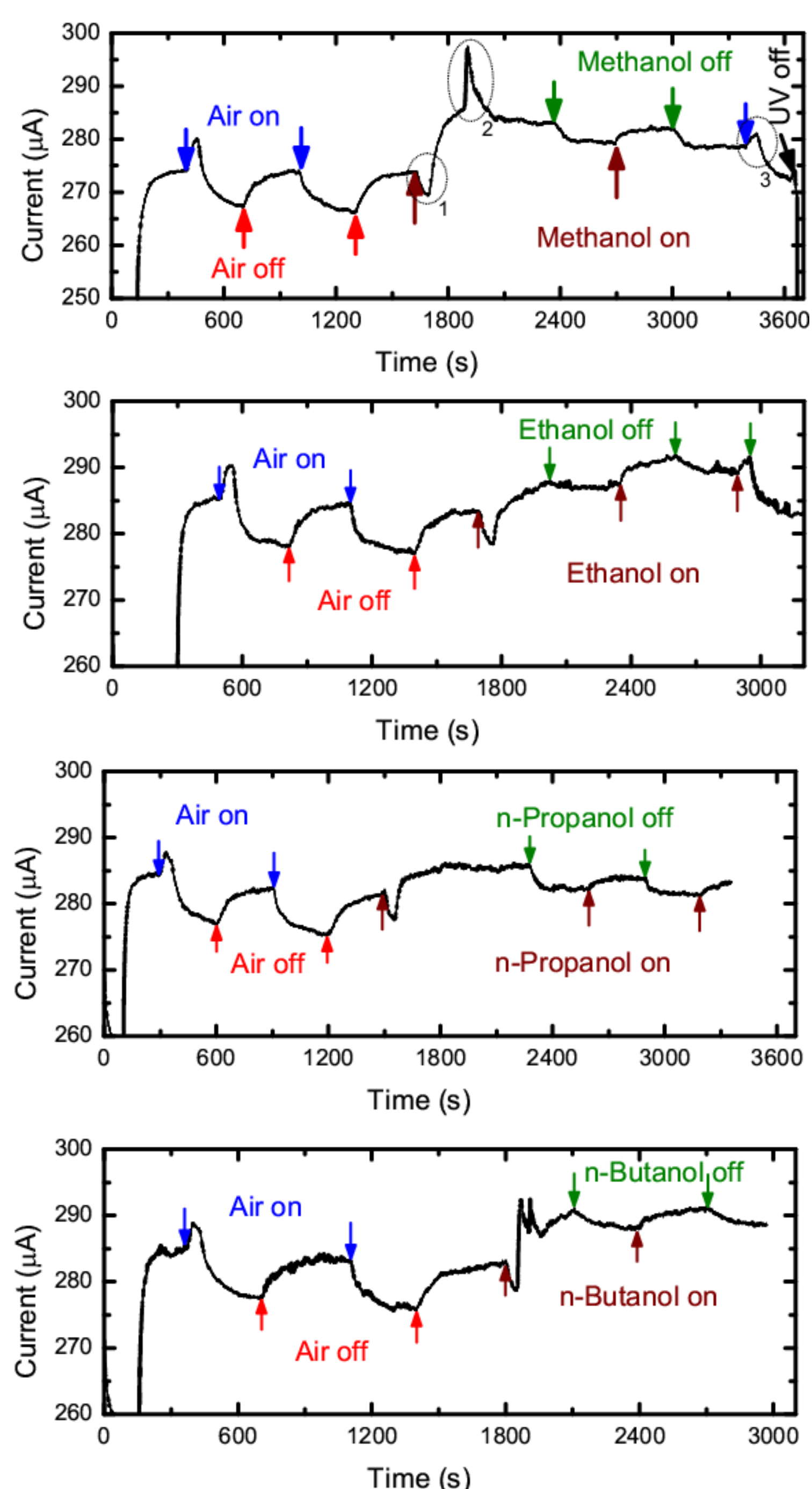


XRD Ω-2θ scan of a 300 nm thick ZnO film.

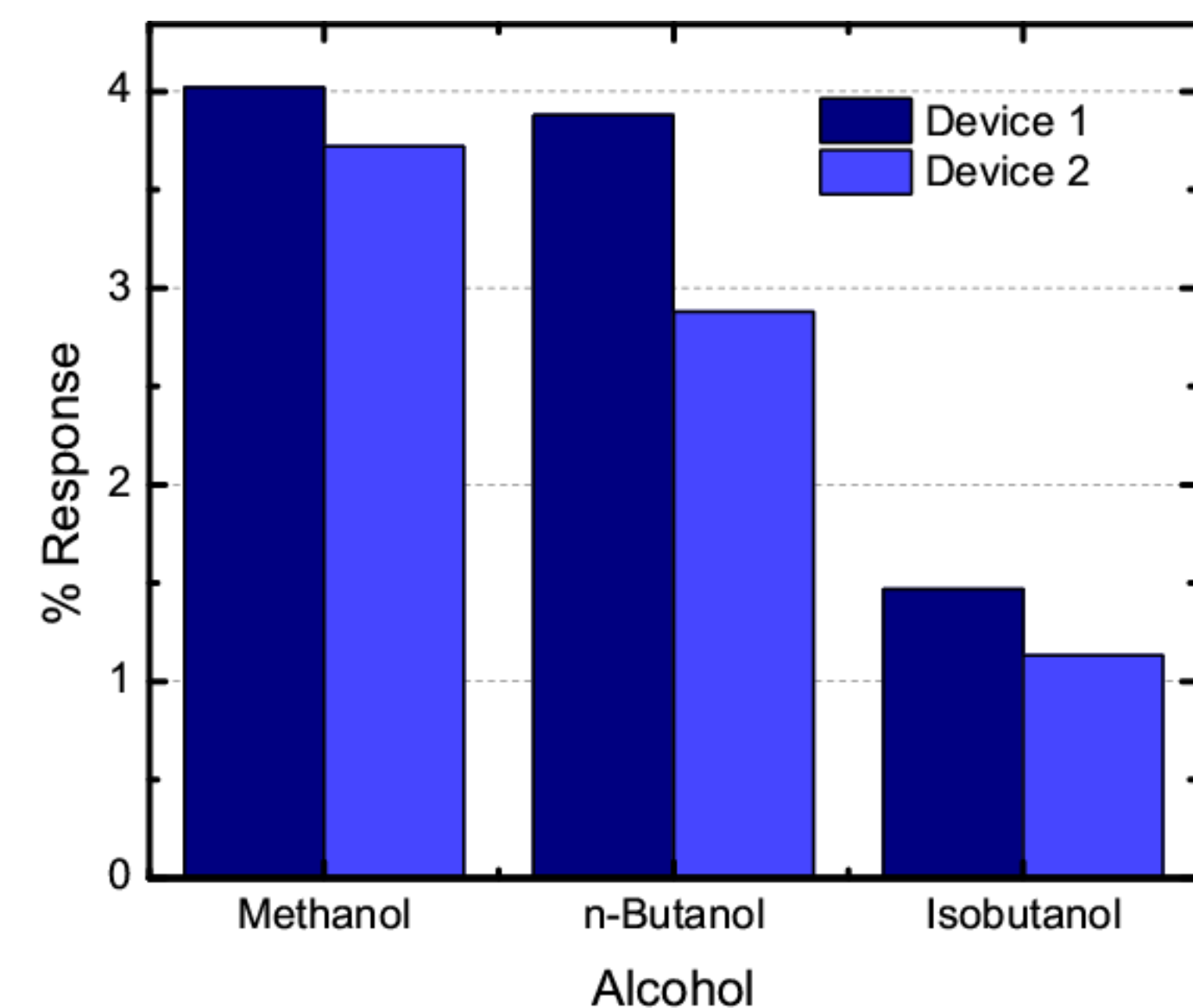
IV. Response to air and N₂



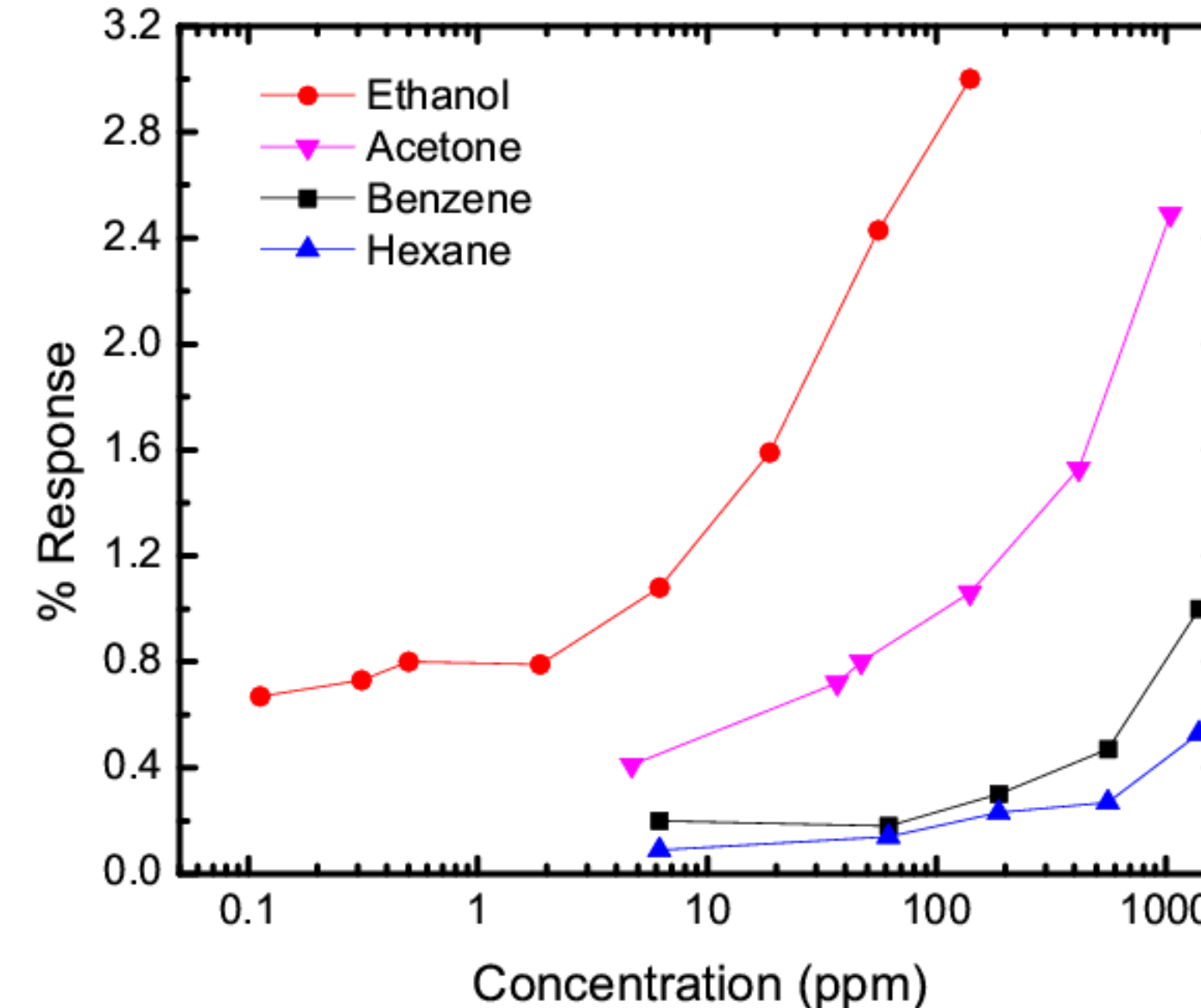
V. Response to alcohols



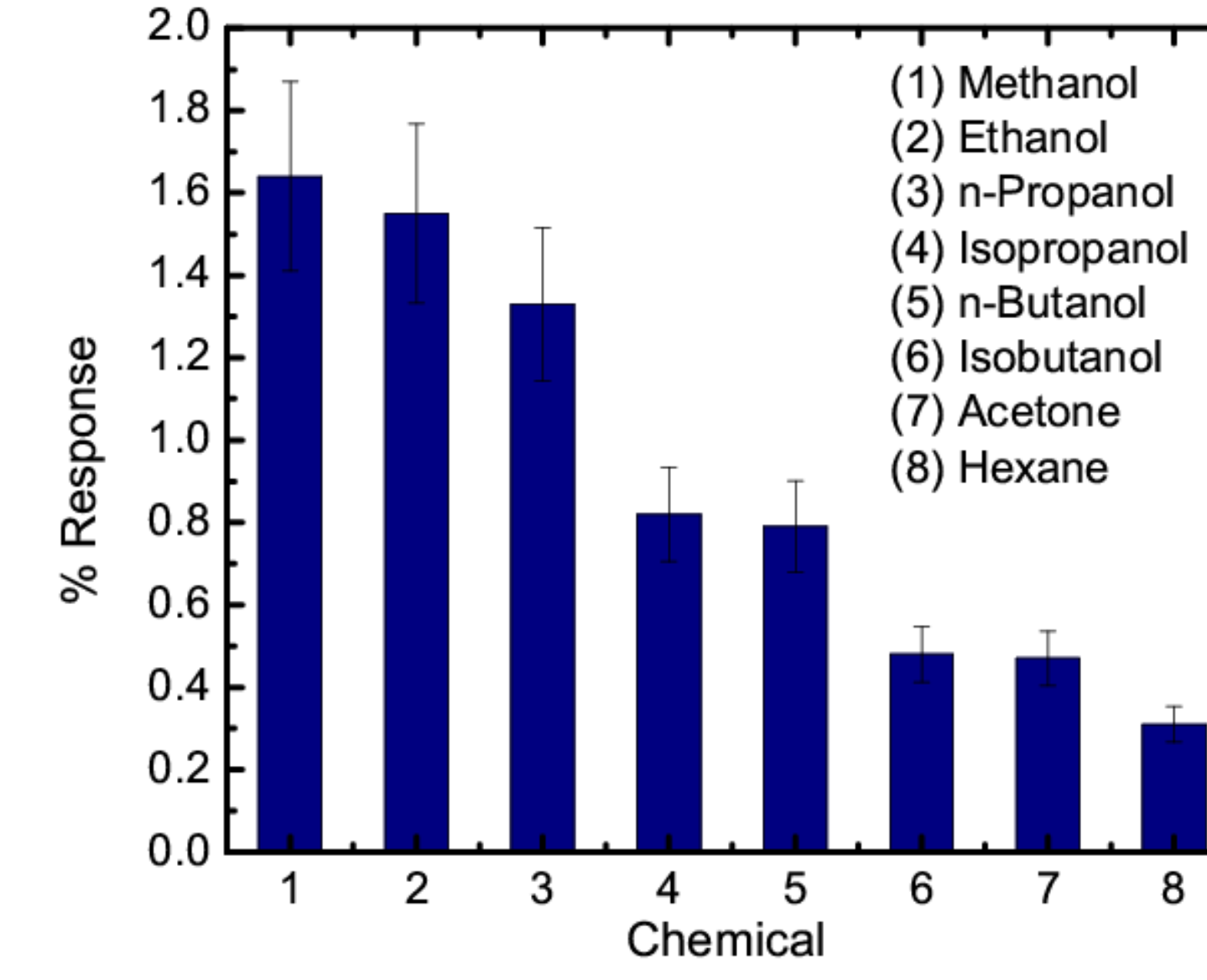
VI. Relative response



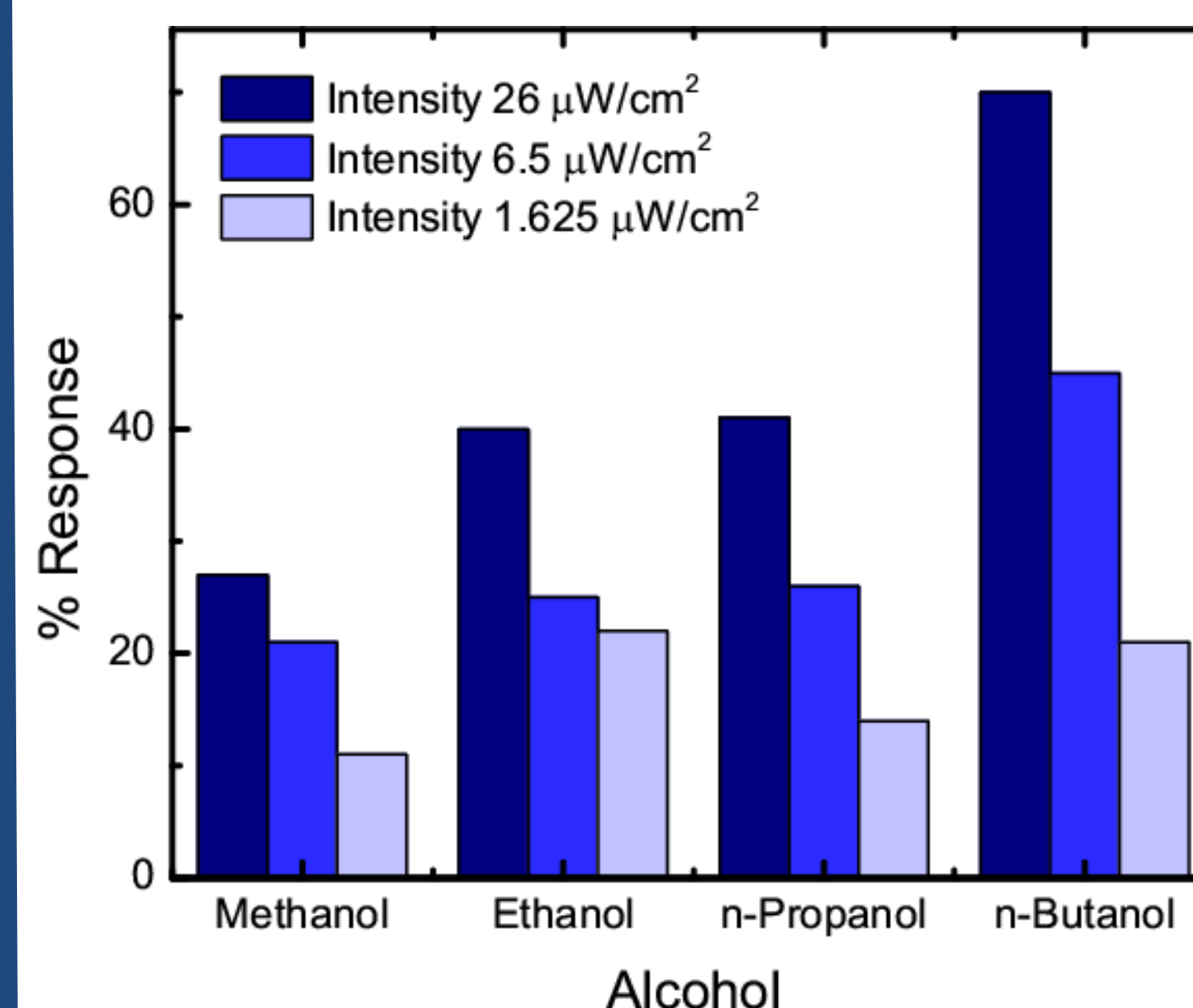
Response of two ZnO NP/ GaN NW devices to methanol and butanol



Response of ZnO NP/ GaN NW devices to different chemicals



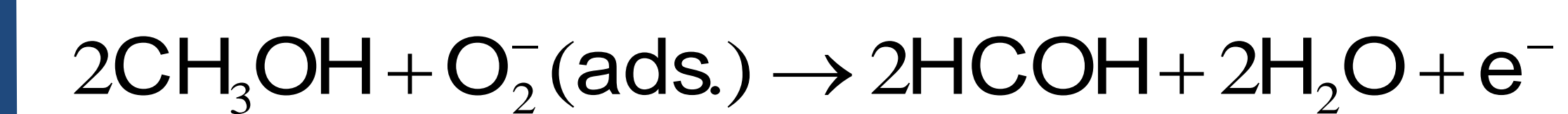
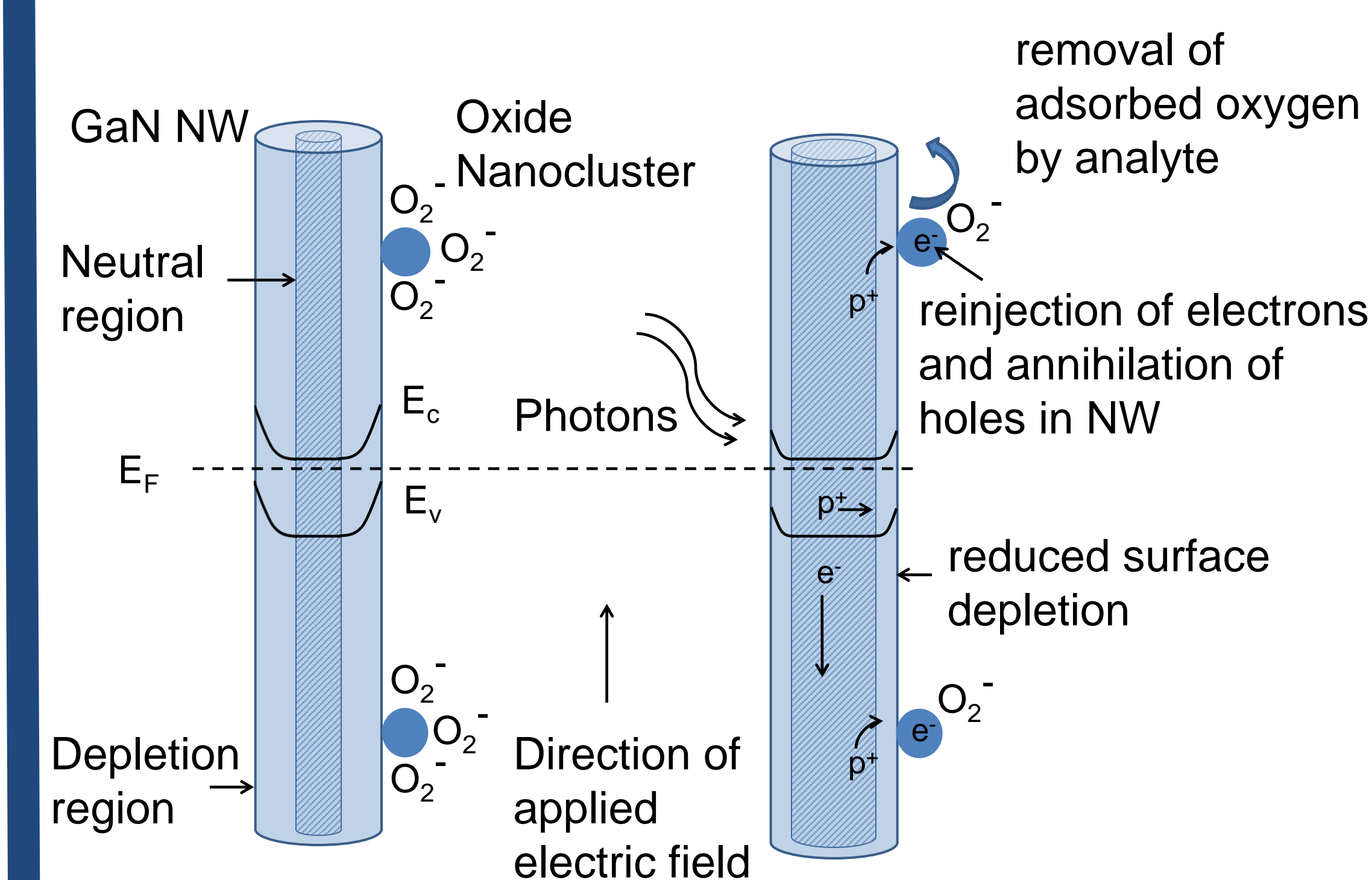
Response of two SnO₂ NP/ GaN NW devices to different gases



Response of ZnO NW device to alcohols under varying intensity

- Study the sensitivity and selectivity of photo-assisted sensing devices with varying light intensity (in collaboration with C.-C. Huang and J.F. Conley, Jr. at School of Electrical Engineering and Computer Science, Oregon State University).
- Interesting to note the response reversal for different alcohols between ZnO NP/GaN NW sensor and ZnO NW sensor.
- Possibly nanoparticles form a sieve on the GaN NW surface reducing the response for the bigger molecules.

VII. Sensing mechanism



Acknowledgement

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